

#### IN THE UNITED STATES PATENT AND TRADEMARK

In re the Application of: YAMAUCHI, Tsunenori

Group Art Unit: 2812

Patent No.: 6,838,349

10/053712

Examiner: C. W. Lattin

Issued:

January 4, 2005

P.T.O. Confirmation No.: 4240

For. SEMICONDUCTOR DEVICE AND METHOD FOR FABRICATING THE SAME

### INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.501

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

March 22, 2005

Sir:

Submitted herewith is a copy of a search report in a European counterpart application dated October 21, 2004 and the cited references.

The cited documents are believed to be pertinent due to citation in the counterpart application. Please place such documents in the file of the above-captioned patent.

In the event any fees are due in connection with this paper, please charge our Deposit Account 01-2340.

Respectfully submitted,

ARMSTRONG, KRATZ, QUINTOS, HANSON & BROOKS, LLP

William G. Kratz, Tr. Attorney for Applicant

Reg. No. 22,631

WGK/nrp Atty. Docket No. **020076** 

Suite 1000, 1725 K Street, N.W. Washington, D.C. 20006

(202) 659-2930

23850

PATENT TRADEMARK OFFICE

Enclosures:

Information Disclosure Statement PTO-1449

Search Report in European counterpart application dated 10/21/04

References (11)

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Information Disclosure Statement PTO-1449

Search Report in European counterpart application dated 10/21/04

References (11)

INFORMATION
DISCLOSURE
<b>CITATION</b>
PTO-1449

Atty. Docket No. 020076 Patent No. 6,838.349

Applicant(s): YAMAUCHI, Tsunenori

Issued: January 4, 2005 Group Art Unit: 2812

### U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
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Europäisches Patentamt

Zweigstelle in Den Haag Recherchenabteilung Eur( in Patent Office

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Département à La Haye Division de la recherche

Fenlon, Christine	Lesley
Haseltine Lake,	_
Imperial House,	
15-19 Kingsway	
London WCŽB 6ŬD	
CDANDE BDETACNE	

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Zeichen/Ref./Réf. P81120EP00/MR	Anmeldung Nr./Application No./Demande n°./Patent Nr./Patent No./Brevet n°. 0.2250610.9-2203-	
Anmelder/Applicant/Demandeur/Patentinhaber/Proprietor/Titulaire FUJITSU LIMITED	-	

## COMMUNICATION

The European Patent Office herewith transmits as an enclosure the European search report for the above-mentioned European patent application.
If applicable, copies of the documents cited in the European search report are attached.
Additional set(s) of copies of the documents cited in the European search report is (are) enclosed as well
The following specifications given by the applicant have been approved by the Search Division:
🗓 abstract 🗀 title
The abstract was modified by the Search Division and the definitive text is attached to this communication.
The tollowing figure will be published together with the abstract

71 OCT 2004

## REFUND OF THE SEARCH FEE

If applicable under Article 10 Rules relating to fees, a separate communication from the Receiving Section on the refund of the search fee will be sent later.





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Y: part docu	icularly relevant if taken alone icularly relevant if combined with anot Iment of the same category nological background	L : document cited for	e n the application or other reasons	shed on, or	
O: non	-written disclosure mediate document	& : member of the sa document			



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#### ANNEX TO THE EUROPEAN SEARCH REPORT ON EUROPEAN PATENT APPLICATION NO.

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This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report. The members are as contained in the European Patent Office EDP file on The European Patent Office is in no way liable for these particulars which are merely given for the purpose of information.

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